

FEATURES

- **Low Supply Current** 55 μ A Max
- **Single-Supply Operation** +5V to +30V
- **Dual-Supply Operation** ± 2.5 V to ± 15 V
- **Low Input Offset Voltage** 250 μ V Max
- **Low Input Offset Voltage Drift** 1.5 μ V/ $^{\circ}$ C Max
- **High Common-Mode Input Range** ... V- to V+ (-1.5V)
- **High CMRR and PSRR** 100dB Min
- **High Open-Loop Gain** 120dB Min
- **No External Components Required**
- **741 Pinout and Nulling**
- Available in Die Form

ORDERING INFORMATION [†]

$T_c = +25^{\circ}$ C V_{OS} MAX (mV)	PACKAGE			OPERATING TEMPERATURE RANGE
	TO-99	CERDIP 8-PIN	PLASTIC 8-PIN	
250	OP20BJ*	OP20BZ	-	MIL
250	OP20FJ	OP20FZ	-	IND
250	-	-	OP20FP	COM
500	-	OP20CZ	-	MIL
500	OP20GJ	OP20GZ	-	IND
500	-	-	OP20GP	COM
1000	OP20HJ	OP20HZ	OP20HS††	XIND
1000	-	-	OP20HP	XIND

* For devices processed in total compliance to MIL-STD-883, add /883 after part number. Consult factory for 883 data sheet.

† Burn-in is available on commercial and industrial temperature range parts in cerDIP, plastic DIP, and TO-can packages.

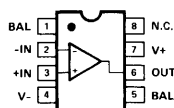
†† For availability and burn-in information on SO and PLCC packages, contact your local sales office.

GENERAL DESCRIPTION

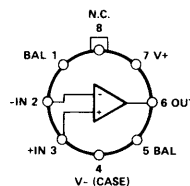
The OP-20 is a monolithic micropower operational amplifier that can be operated from a single power supply of +5V to +30V, or from dual supplies of ± 2.5 V to ± 15 V. The input voltage range extends to the negative rail, therefore input signals down to zero volts can be accommodated when operating from a single supply.

Precision performance in high-gain applications is readily obtained when using the OP-20. The B/F grade features a maximum input offset voltage of 250 μ V, minimum CMRR of 95dB, and open-loop gain of over 500,000. Quiescent supply current is a maximum of only 55 μ A at ± 2.5 V or 80 μ A at ± 15 V. The low input offset, high gain, and low power consumption brings precision performance to portable instruments, satellites, missile control systems, and many other battery-powered applications.

PIN CONNECTIONS



**EPOXY MINI-DIP
(P-Suffix)**

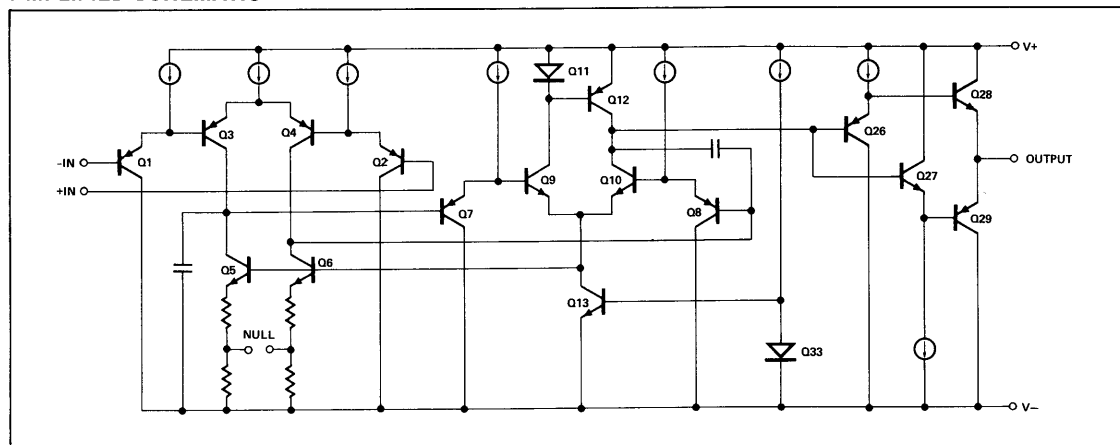


**TO-99
(J-Suffix)**

**8-PIN HERMETIC DIP
(Z-Suffix)**

**8-PIN SO
(S-Suffix)**

SIMPLIFIED SCHEMATIC



OP-20

ABSOLUTE MAXIMUM RATINGS (Note 1)

Supply Voltage	±18V
Differential Input Voltage	±30V
Input Voltage	Supply Voltage
Output Short-Circuit Duration	Indefinite
Storage Temperature Range	
J and Z Packages	-65°C to +150°C
P Package	-65°C to +125°C
Operating Temperature Range	
OP-20B, OP-20C (J, Z)	-55°C to +125°C
OP-20F, OP-20G (J, Z)	-25°C to +85°C
OP-20H (S, P, J, Z)	-40°C to +85°C
OP-20FP, OP-20GP	0°C to +70°C
Lead Temperature Range (Soldering, 60 sec)	300°C
Junction Temperature	-65°C to +150°C

PACKAGE TYPE	θ_{JA} (NOTE 2)	θ_{JC}	UNITS
TO-99 (J)	150	18	°C/W
8-Pin Hermetic DIP (Z)	148	16	°C/W
8-Pin Plastic DIP (P)	103	43	°C/W
8-Pin SO (S)	158	43	°C/W

NOTES:

1. Absolute maximum ratings apply to both DICE and packaged parts, unless otherwise noted.
2. θ_{JA} is specified for worst case mounting conditions, i.e., θ_{JA} is specified for device in socket for TO, CerDIP and P-DIP packages; θ_{JA} is specified for device soldered to printed circuit board for SO package.

ELECTRICAL CHARACTERISTICS at $V_S = \pm 2.5V$ to $\pm 15V$, $T_A = +25^\circ C$, unless otherwise noted.

PARAMETER	SYMBOL	CONDITIONS	OP-20B/F			OP-20C/G			OP-20H			UNITS
			MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
Input Offset Voltage	V_{OS}	$V_S = \pm 15V$	—	55	250	—	150	500	—	300	1000	μV
Input Offset Current	I_{OS}	$V_{CM} = 0$	—	0.15	1.5	—	0.2	2.5	—	0.3	4.0	nA
Input Bias Current	I_B	$V_{CM} = 0$	—	12	25	—	14	30	—	16	40	nA
Input Voltage Range	IVR	$V_+ = +5V,$ $V_- = 0V$ $V_S = \pm 15V$	0/3.5	—	—	0/3.5	—	—	0/3.5	—	—	V
Common-Mode Rejection Ratio	CMRR	$V_+ = +5V, V_- = 0V$ $0V \leq V_{CM} \leq 3.5V$ $V_S = \pm 15V$	95	105	—	90	95	—	85	90	—	dB
		$-15V \leq V_{CM} \leq 13.5V$	100	110	—	94	105	—	90	100	—	dB
Power Supply Rejection Ratio	PSRR	$V_S = \pm 2.5V$ to $\pm 15V$ and $V_- = 0V,$ $V_+ = 5V$ to $30V$	—	4	6	—	6	10	—	10	32	$\mu V/V$
Large-Signal Voltage Gain	A_{VO}	$V_+ = +5V, V_- = 0V$ $1V \leq V_O \leq 3.5V$ $V_S = \pm 15V, V_O = \pm 10V$ $R_L = 25k\Omega$	300	500	—	200	500	—	—	500	—	V/mV
		$V_+ = 5V, V_- = 0V$ $R_L = 10k\Omega$ $V_S = \pm 15V,$ $R_L = 25k\Omega$	1000	2000	—	800	2000	—	—	500	1000	—
Output Voltage Swing	V_O	$V_+ = 5V, V_- = 0V$ $R_L = 10k\Omega$ $V_S = \pm 15V,$ $R_L = 25k\Omega$	0.6/4.1	—	—	0.7/4.1	—	—	0.8/4.0	—	—	V
Closed-Loop Bandwidth	BW	$A_{VCL} = +1.0,$ $R_L = 10k\Omega$	—	100	—	—	100	—	—	100	—	kHz
Slew Rate	SR	$V_S = \pm 15V$ $R_L = 25k\Omega$	—	0.05	—	—	0.05	—	—	0.05	—	V/ μs
Supply Current	I_{SY}	$V_S = \pm 2.5V,$ No Load	—	40	55	—	44	63	—	45	70	μA
		$V_S = \pm 15V,$ No Load	—	55	80	—	57	85	—	60	95	μA

ELECTRICAL CHARACTERISTICS at $V_S = \pm 2.5V$ to $\pm 15V$, $-55^\circ C \leq T_A \leq +125^\circ C$ for OP-20BJ/BZ and OP-20CZ, $-25^\circ C \leq T_A \leq +85^\circ C$ for OP-20FJ/FZ and OP-20GJ/GZ, and $0^\circ C \leq T_A \leq +70^\circ C$ for OP-20FP, OP-20GP, and $-40^\circ C \leq T_A \leq +85^\circ C$ for OP-20HZ, OP-20HJ, and OP-20HP/HS, unless otherwise noted.

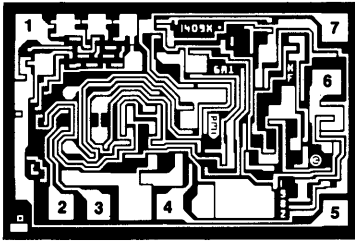
PARAMETER	SYMBOL	CONDITIONS	OP-20B/F			OP-20C/G			OP-20H			UNITS
			MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
Average Input Offset Voltage Drift (Note 1)	TCV _{OS}	Unnulled	—	0.75	1.5	—	1.0	3.0	—	1.5	7.0	$\mu V/^\circ C$
Input Offset Voltage	V _{OS}	V _S = $\pm 15V$	—	155	400	—	250	800	—	500	1700	μV
Input Offset Current	I _{OS}	V _{CM} = 0	—	0.5	2.5	—	1.0	3.5	—	1.5	5.0	nA
Input Bias Current	I _B	V _{CM} = 0	—	12	27	—	14	33	—	16	45	nA
Input Voltage Range	IVR	V ₊ = +5V, V ₋ = 0V V _S = $\pm 15V$	0/3.2 -15/13.2	—	—	0/3.2 -15/13.2	—	—	0/3.2 -15/13.2	—	—	V
Common-Mode Rejection Ratio	CMRR	V ₊ = +5V, V ₋ = 0V 0V \leq V _{CM} \leq 3.2V V _S = $\pm 15V$	90	100	—	85	90	—	80	85	—	dB
		-15V \leq V _{CM} \leq 13.2V	96	110	—	90	105	—	85	100	—	
Power Supply Rejection Ratio	PSRR	V _S = $\pm 2.5V$ to $\pm 15V$ V ₋ = 0V, V ₊ = 5V to 30V	—	4	10	—	6	18	—	10	32	$\mu V/V$
			—	4	10	—	6	18	—	10	57	
Large-Signal Voltage Gain	A _{VO}	V _S = $\pm 15V$, V _O = $\pm 10V$ R _L = 50k Ω	500	700	—	400	600	—	250	400	—	V/mV
Output Voltage Swing	V _O	V ₊ = 5V, V ₋ = 0V, R _L = 50k Ω , V _S = $\pm 15V$, R _L = 50k Ω	0.8/4.0 ± 14.0	—	—	0.9/3.9 ± 13.9	—	—	1.0/3.8 ± 13.9	—	—	V
Supply Current	I _{SY}	V _S = $\pm 2.5V$, No Load or +5V, 0V	—	50	65	—	53	75	—	55	85	μA
		V _S = $\pm 15V$, No Load	—	64	95	—	68	100	—	72	115	

NOTE:

1. Sample tested.

OP-20

DICE CHARACTERISTICS



1. BALANCE
2. INVERTING INPUT
3. NONINVERTING INPUT
4. V-
5. BALANCE
6. OUTPUT
7. V+

DIE SIZE 0.069 x 0.047 inch, 3174 sq. mils
(1.75 x 1.17 mm, 2.05 sq. mm)

WAFER TEST LIMITS at $V_S = \pm 15V$, $T_A = 25^\circ C$, unless otherwise noted.

PARAMETER	SYMBOL	CONDITIONS	OP-20N LIMIT	OP-20G LIMIT	OP-20GR LIMIT	UNITS
Input Offset Voltage	V_{OS}		300	600	1000	μV MAX
Input Offset Current	I_{OS}		1.5	2.5	4.0	nA MAX
Input Bias Current	I_B		25	30	40	nA MAX
Input Voltage Range	IVR	$V_+ = +5V, V_- = 0V$ $V_S = \pm 15V$	0/3.5 -15/13.5	0/3.5 -15/13.5	0/3.5 -15/13.5	V MIN
Common-Mode Rejection Ratio	CMRR	$V_+ = +5V, V_- = 0V, 0V \leq V_{CM} \leq +3.5V$ $V_S = \pm 15V, -15V \leq V_{CM} \leq \pm 13.5V$	95 100	90 94	85 90	dB MIN
Power Supply Rejection Ratio	PSRR	$V_S = \pm 2.5V$ to $\pm 15V$ $V_- = 0V, V_+ = +5V$ to $+30V$	6	10	32	$\mu V/V$ MAX
Large-Signal Voltage Gain	A_{VO}	$R_L = 25k\Omega$ $V_O = \pm 10V$	1000	800	500	V/mV MIN
Output Voltage Swing	V_O	$R_L = 10k\Omega, V_+ = +5V, V_- = 0V$ $R_L = 25k\Omega, V_S = \pm 15V$	0.7/4.1 ± 14.1	0.8/4.1 ± 14.1	0.9/4.0 ± 14.0	V MIN
Supply Current	I_{SY}	$V_S = \pm 2.5V$, No Load $V_S = \pm 15V$, No Load	55 80	63 85	70 95	μA MAX

NOTE:

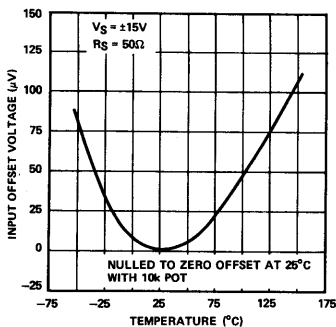
Electrical tests are performed at wafer probe to the limits shown. Due to variations in assembly methods and normal yield loss, yield after packaging is not guaranteed for standard product dice. Consult factory to negotiate specifications based on dice lot qualification through sample lot assembly and testing.

TYPICAL ELECTRICAL CHARACTERISTICS at $V_S = \pm 15V$, $T_A = +25^\circ C$, unless otherwise noted.

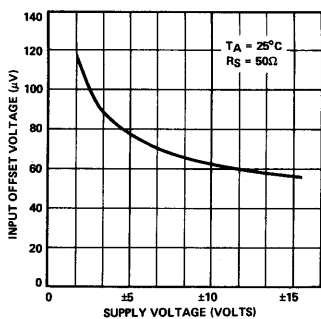
PARAMETER	SYMBOL	CONDITIONS	OP-20N TYPICAL	OP-20G TYPICAL	OP-20GR TYPICAL	UNITS
Average Input Offset Voltage Drift	TCV_{OS} TCV_{OSn}	Unnulled Nulled, $R_P = 10k\Omega$	1.0 1.0	1.5 1.5	2.5 2.5	$\mu V/^\circ C$
Large-Signal Voltage Gain	A_{VO}	$R_L = 25k\Omega$	2000	2000	1000	V/mV

TYPICAL PERFORMANCE CHARACTERISTICS

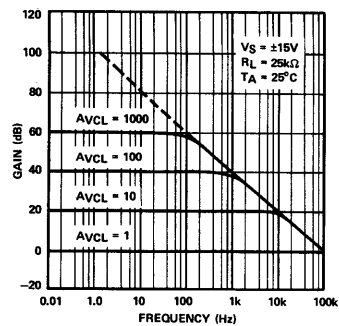
TRIMMED OFFSET VOLTAGE vs TEMPERATURE



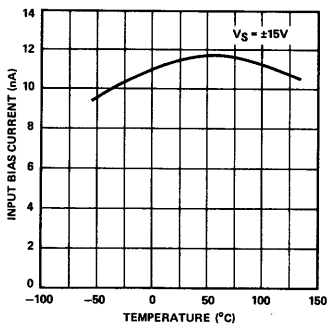
INPUT OFFSET VOLTAGE vs POWER SUPPLY VOLTAGE



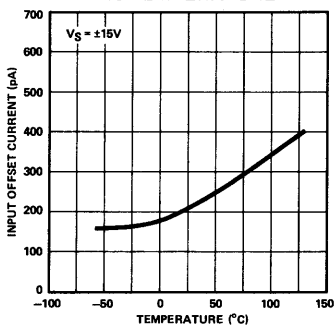
CLOSED-LOOP GAIN vs FREQUENCY



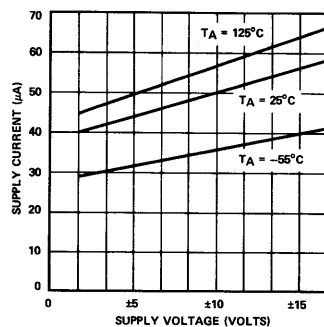
INPUT BIAS CURRENT vs TEMPERATURE



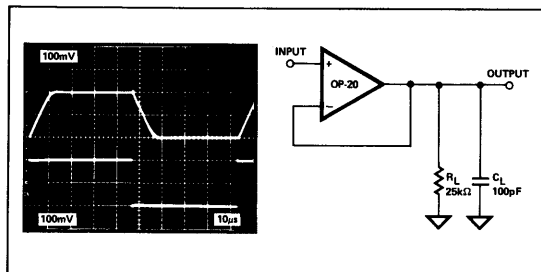
INPUT OFFSET CURRENT vs TEMPERATURE



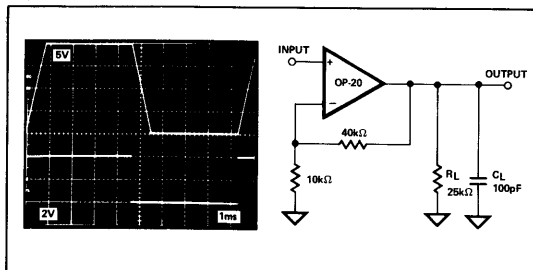
SUPPLY CURRENT vs SUPPLY VOLTAGE



SMALL-SIGNAL TRANSIENT RESPONSE



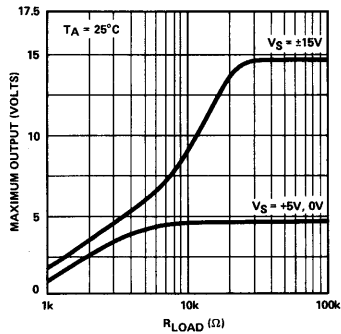
LARGE-SIGNAL TRANSIENT RESPONSE



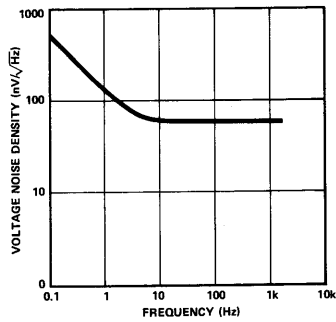
OP-20

TYPICAL PERFORMANCE CHARACTERISTICS

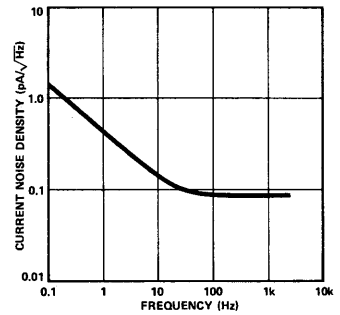
MAXIMUM OUTPUT VOLTAGE vs LOAD RESISTANCE



VOLTAGE NOISE DENSITY vs FREQUENCY

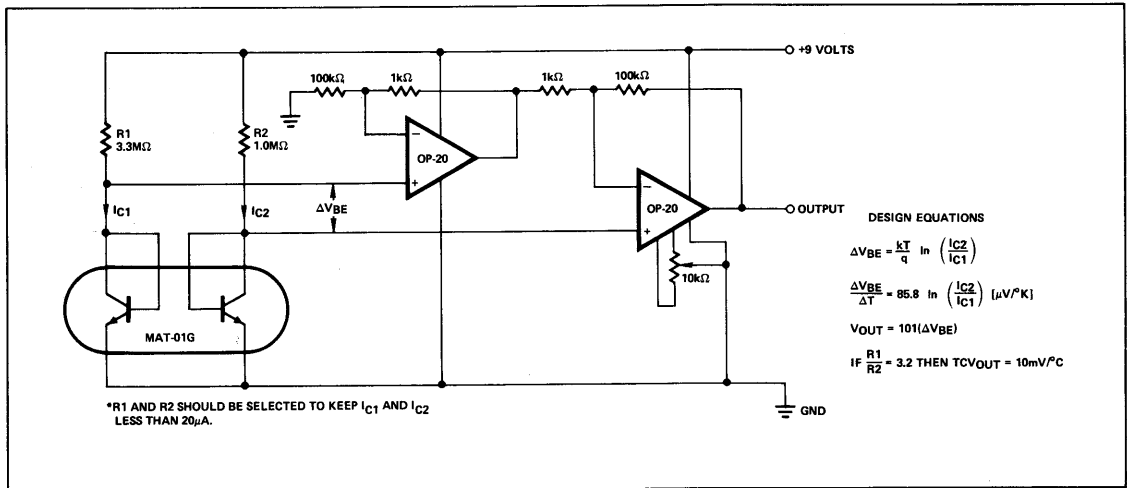


CURRENT NOISE DENSITY vs FREQUENCY



TYPICAL APPLICATIONS

TEMPERATURE SENSOR



FEATURES

- **Low Supply Current** 230 μ A Max
- **Wide Supply Range** $\pm 2.5V$ to $\pm 15V$
- **Low Input Offset Voltage** 100 μ V Max
- **Low Input Offset Voltage Drift** 1.0 μ V/ $^{\circ}$ C Max
- **High Common-Mode Input Range** $V- (+0.5V)$ to $V+ (-1.5V)$
- **High CMRR and PSRR** 100dB Min
- **High Open-Loop Gain** 1000V/mV Min
- **125 $^{\circ}$ C Temperature Tested Dice**

GENERAL DESCRIPTION

The OP-21 is a precision low-power operational amplifier offering the benefits of low offset voltage and high slew rate with the advantages of low power. A supply range of $\pm 2.5V$ to $\pm 15V$ allows a wide range of applications.

Two military temperature range models and three industrial temperature range models are available in TO-99 cans and 8-Pin hermetic DIPs. Industrial temperature range models are also available in 8-Pin epoxy DIPs. See OP-221 for dual and OP-421 for quad versions of the OP-21.

2

ORDERING INFORMATION [†]

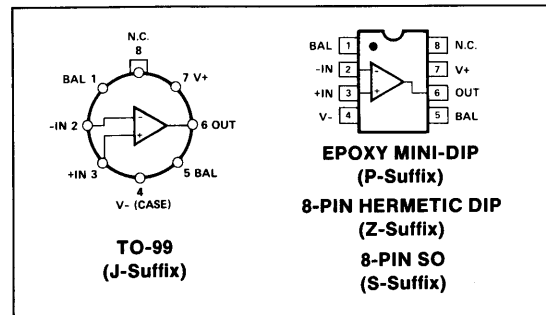
$T_a = +25^{\circ}C$ $V_{os} \text{ MAX}$ (μ V)	PACKAGE			OPERATING TEMPERATURE RANGE
	TO-99	CERDIP 8-PIN	PLASTIC 8-PIN	
100	OP21AJ	OP21AZ*	—	MIL
100	—	OP21EZ	—	IND
200	OP21FJ	OP21FZ	OP21FP	IND
500	OP21GJ	—	OP21GP	XIND
500	—	—	OP21HS ^{††}	XIND

* For devices processed in total compliance to MIL-STD-883, add /883 after part number. Consult factory for 883 data sheet.

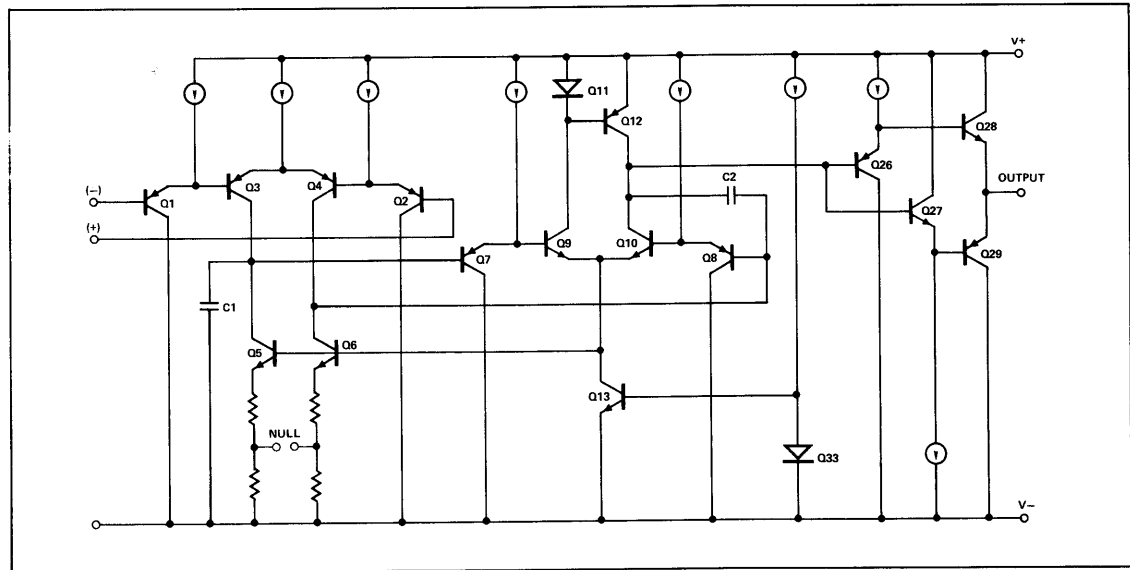
[†] Burn-in is available on commercial and industrial temperature range parts in CerDIP, plastic DIP, and TO-can packages.

^{††} For availability and burn-in information on SO and PLCC packages, contact your local sales office.

PIN CONNECTIONS



SIMPLIFIED SCHEMATIC



OP-21

ABSOLUTE MAXIMUM RATINGS (Note 2)

Supply Voltage	±18V
Differential Input Voltage	±30V
Input Voltage	Supply Voltage
Output Short-Circuit Duration	Indefinite
Storage Temperature Range	
J and Z Packages	-65°C to +125°C
P Package	-65°C to +125°C
Operating Temperature Range	
OP-21A	-55°C to +125°C
OP-21E, OP-21F	-25°C to +85°C
OP-21HS, OP-21G	-40°C to +85°C

Junction Temperature (T _J)	-65°C to +150°C
Lead Temperature (Soldering, 60 sec)	300°C

PACKAGE TYPE	θ _{JA} (Note 1)	θ _{JC}	UNITS
TO-99 (J)	150	18	°C/W
8-Pin Hermetic DIP (Z)	148	16	°C/W
8-Pin Plastic DIP (P)	103	43	°C/W
8-Pin SO (S)	158	43	°C/W

NOTES:

1. θ_{JA} is specified for worst case mounting conditions, i.e., θ_{JA} is specified for device in socket for TO, CerDIP, P-DIP, and LCC packages; θ_{JA} is specified for device soldered to printed circuit board for SO package.
2. Absolute maximum ratings apply to both DICE and packaged parts, unless otherwise noted.

ELECTRICAL CHARACTERISTICS at V_S = ±2.5V to ±15V and T_A = +25°C, unless otherwise noted.

PARAMETER	SYMBOL	CONDITIONS	OP-21A/E			OP-21F			OP-21G/H			UNITS
			MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
Input Offset Voltage	V _{OS}	V _S = ±15V	—	40	100	—	150	200	—	300	500	μV
Input Offset Current	I _{OS}	V _{CM} = 0	—	0.6	4	—	0.8	5	—	1.2	6	nA
Input Bias Current	I _B	V _{CM} = 0	—	50	100	—	60	120	—	70	150	nA
Input Voltage Range	IVR	V _S = ±15V	-14.5/13.5	—	—	-14.5/13.5	—	—	-14.5/13.5	—	—	V
Common-Mode Rejection Ratio	CMRR	V _S = ±15V, No Load -14.5V ≤ V _{CM} ≤ 13.5V	100	110	—	90	105	—	84	100	—	dB
Power Supply Rejection Ratio	PSRR	V _S = ±2.5V to ±15V, No Load	—	2	6	—	4	10	—	10	32	μV/V
Large-Signal Voltage Gain	A _{VO}	V _S = ±15V, R _L = 10kΩ, V _O ±10V	1000	2000	—	500	1500	—	500	1000	—	V/mV
Output Voltage Swing	V _O	V _S = ±15V, R _L = 10kΩ	-13.7/14.0	—	—	-13.7/13.9	—	—	-13.6/13.8	—	—	V
Slew Rate	SR	C _L = 100pF, R _L = 25kΩ	—	0.25	—	—	0.25	—	—	0.25	—	V/μs
Closed-Loop Bandwidth	BW	A _{VCL} = +1, R _L = 10kΩ	—	600	—	—	600	—	—	600	—	kHz
Supply Current	I _{SY}	V _S = ±2.5V, No Load	—	170	230	—	180	275	—	190	300	μA
		V _S = ±15V, No Load	—	230	300	—	235	360	—	250	420	

ELECTRICAL CHARACTERISTICS at $V_S = \pm 2.5V$ to $\pm 15V$, $-55^\circ C \leq T_A \leq +125^\circ C$ for OP-21A, $-25^\circ C \leq T_A \leq +85^\circ C$ for OP-21E and OP-21F, $-40^\circ C \leq T_A \leq +85^\circ C$ for OP-21G and OP-21H, unless otherwise noted.

PARAMETER	SYMBOL	CONDITIONS	OP-21A/E			OP-21F			OP-21G/H			UNITS
			MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
Average Input Offset Voltage Drift (Notes 1, 2)	TCV _{OS}	Unnulled	—	0.5	1.0	—	1.0	2.0	—	2.5	5.0	$\mu V/^\circ C$
	TCV _{OSn}	Nulled	—	—	—	—	—	—	—	—	—	
Input Offset Voltage	V _{OS}		—	75	200	—	200	500	—	500	1000	μV
Input Offset Current	I _{OS}	V _{CM} = 0	—	0.7	5	—	0.7	6	—	0.8	8	nA
Input Bias Current	I _B	V _{CM} = 0	—	50	110	—	60	130	—	70	165	nA
Input Voltage Range	IVR		-14.3/13.2	—	—	-14.3/13.2	—	—	-14.3/13.2	—	—	V
Common-Mode Rejection Ratio	CMRR	No Load, V _S = $\pm 15V$, -14.5V \leq V _{CM} $\leq 13.2V$	96	105	—	86	100	—	80	95	—	dB
Power Supply Rejection Ratio	PSRR	V _S = $\pm 2.5V$ to $\pm 15V$, No Load	—	4	10	—	6	18	—	18	57	$\mu V/V$
Large-Signal Voltage Gain	A _{VO}	V _S = $\pm 15V$, R _L = 20k Ω , V _O = $\pm 10V$	500	1500	—	250	1300	—	250	1000	—	V/mV
Output Voltage Swing	V _O	V _S = $\pm 15V$, R _L = 20k Ω	-13.5/13.8	—	—	-13.5/13.7	—	—	-13.5/13.6	—	—	V
Supply Current	I _{SY}	V _S = $\pm 2.5V$, No Load	—	205	275	—	215	330	—	230	360	μA
		V _S = $\pm 15V$, No Load	—	275	360	—	285	430	—	300	500	

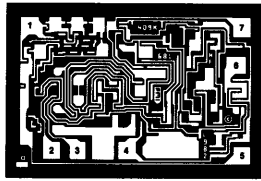
NOTES:

1. Sample tested.
2. TCV_{OSn} is guaranteed by unnulled TCV_{OS} and device design.

2

OP-21

DICE CHARACTERISTICS (125° C TESTED DICE AVAILABLE)



DIE SIZE 0.069 × 0.046 inch, 3174 sq. mils
(1.75 × 1.17 mm, 2.05 sq. mm)

1. BALANCE
2. INVERTING INPUT
3. NONINVERTING INPUT
4. V-
5. BALANCE
6. OUTPUT
7. V+

ELECTRICAL CHARACTERISTICS at $V_S = \pm 15V$, $T_A = +25^\circ C$ for OP-21N and OP-21G devices; $T_A = +125^\circ C$ for OP-21NT and OP-21GT devices, unless otherwise noted.

PARAMETER	SYMBOL	CONDITIONS	OP-21NT LIMIT	OP-21N LIMIT	OP-21GT LIMIT	OP-21G LIMIT	UNITS
Input Offset Voltage	V_{OS}		200	100	500	200	μV MAX
Input Offset Current	I_{OS}	$V_{CM} = 0$	4	4	5	5	nA MAX
Input Bias Current	I_B	$V_{CM} = 0$	100	100	120	120	nA MAX
Input Voltage Range	IVR		-14.3 +13.5	-14.5 +13.5	-14.3 +13.5	-14.5 +13.5	V MIN
Common-Mode Rejection Ratio	CMRR	No Load CMVR = IVR	96	100	86	90	dB MIN
Power Supply Rejection Ratio	PSRR	$V_S = \pm 2.5V$ to $\pm 15V$ No Load	10	6	18	10	$\mu V/V$ MAX
Large-Signal Voltage Gain	A_{VO}	$R_L = 10k\Omega$, $V_O = \pm 10V$	500	1000	250	500	V/mV MIN
Output Voltage Swing	V_O	$R_L = 10k\Omega$	-13.5 +13.8	-13.7 +14.0	-13.5 +13.8	-13.7 +13.9	V MIN
Supply Current	I_{SY}	No Load	300	300	360	360	μA MAX

NOTES:

For 25° C characteristics of NT & GT devices, see N & G characteristics respectively.

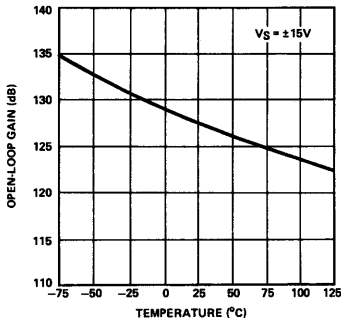
Electrical tests are performed at wafer probe to the limits shown. Due to variations in assembly methods and normal yield loss, yield after packaging is not guaranteed for standard product dice. Consult factory to negotiate specifications based on dice lot qualification through sample lot assembly and testing.

TYPICAL ELECTRICAL CHARACTERISTICS at $V_S = \pm 15V$, $T_A = +25^\circ C$, unless otherwise noted.

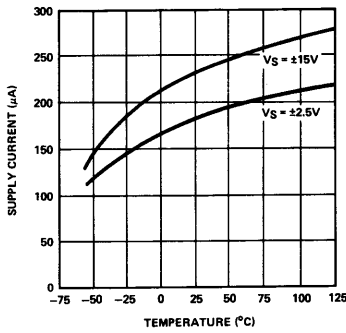
PARAMETER	SYMBOL	CONDITIONS	OP-21NT TYPICAL	OP-21N TYPICAL	OP-21GT TYPICAL	OP-21G TYPICAL	UNITS
Average Input Offset Voltage Drift	TCV_{OS}	Unnulled	0.5	0.5	1	1	$\mu V/^\circ C$
Nullled Input Offset Voltage Drift	TCV_{OSn}	Nullled, $R_p = 10k\Omega$	0.5	0.5	1	1	$\mu V/^\circ C$
Large-Signal Voltage Gain	A_{VO}	$R_L = 10k\Omega$	2000	2000	1500	1500	V/mV
Slew Rate	SR	$R_L = 25k\Omega$ $C_L = 100pF$	0.25	0.25	0.25	0.25	V/ μs
Closed-Loop Bandwidth	BW	$A_{VCL} = +1$ $R_L = 10k\Omega$	600	600	600	600	kHz

TYPICAL PERFORMANCE CHARACTERISTICS

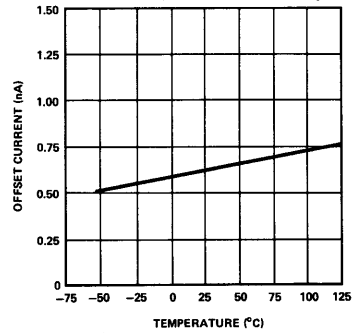
OPEN-LOOP GAIN vs TEMPERATURE



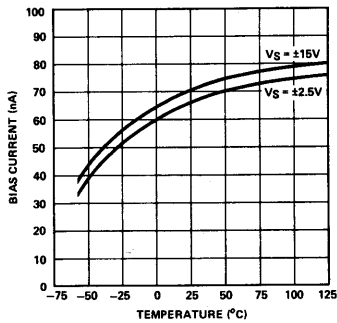
SUPPLY CURRENT vs TEMPERATURE



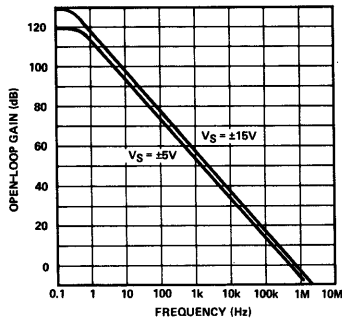
OFFSET CURRENT vs TEMPERATURE



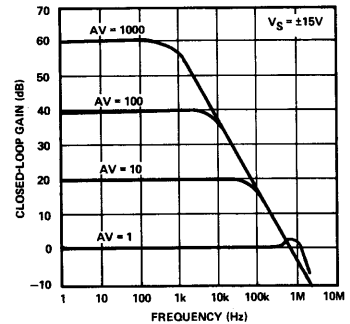
BIAS CURRENT vs TEMPERATURE



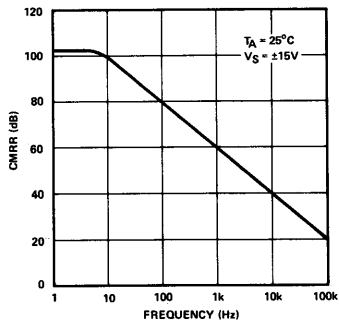
OPEN-LOOP GAIN vs FREQUENCY



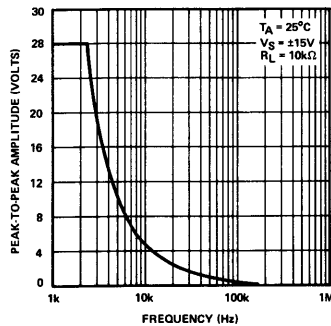
CLOSED-LOOP GAIN vs FREQUENCY



CMRR vs FREQUENCY



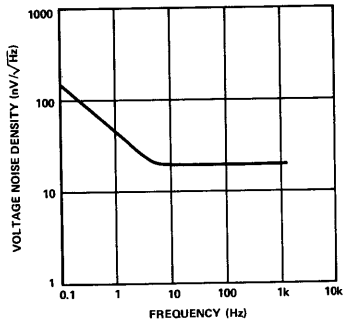
MAXIMUM OUTPUT SWING vs FREQUENCY



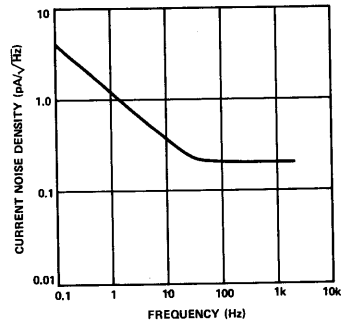
2

TYPICAL PERFORMANCE CHARACTERISTICS

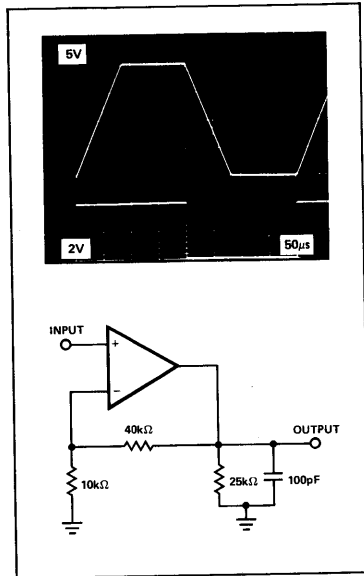
VOLTAGE NOISE DENSITY vs FREQUENCY



CURRENT NOISE DENSITY vs FREQUENCY



NONINVERTING LARGE-SIGNAL RESPONSE



NONINVERTING SMALL-SIGNAL RESPONSE

